

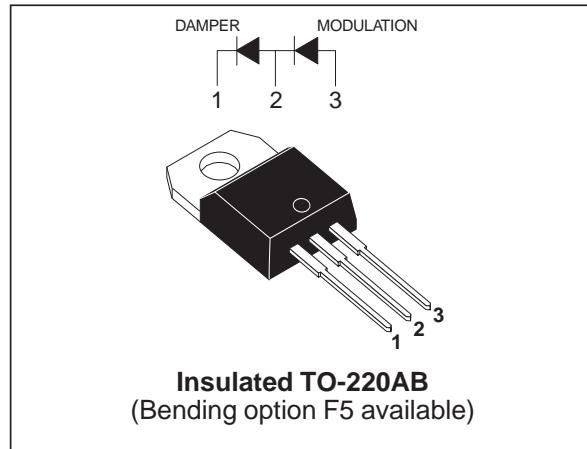
## DAMPER + MODULATION DIODE FOR VIDEO

### MAIN PRODUCT CHARACTERISTICS

|                       | MODUL | DAMPER |
|-----------------------|-------|--------|
| I <sub>F(AV)</sub>    | 3 A   | 6 A    |
| V <sub>RRM</sub>      | 600 V | 1500 V |
| T <sub>rr</sub> (max) | 50 ns | 125 ns |
| V <sub>F</sub> (max)  | 1.4 V | 1.7 V  |

### FEATURES AND BENEFITS

- Full kit in one package
- High breakdown voltage capability
- Very fast recovery diode
- Specified turn on switching characteristics
- Low static and peak forward voltage drop for low dissipation
- Insulated version:  
Insulated voltage = 2500 V<sub>RMS</sub>  
Capacitance = 7 pF
- Planar technology allowing high quality and best electrical characteristics
- Outstanding performance of well proven DTV as damper and new Turboswitch2 as modulation



### DESCRIPTION

High voltage semiconductor especially designed for horizontal deflection stage in standard and high resolution video display with E/W correction.

The insulated TO-220AB package includes both the DAMPER diode and the MODULATION diode. Assembled on automated line, it offers excellent insulating and dissipating characteristics, thanks to the internal ceramic insulation layer.

### ABSOLUTE RATINGS (limiting values, per diode)

| Symbol           | Parameter   | Value         |        | Unit |
|------------------|---|---------------|--------|------|
|                  |   | MODUL         | DAMPER |      |
| V <sub>RRM</sub> | Repetitive peak reverse voltage                               | 600           | 1500   | V    |
| I <sub>FSM</sub> | Surge non repetitive forward current<br>tp = 10 ms sinusoidal | 35            | 80     | A    |
| T <sub>stg</sub> | Storage temperature range                                     | - 40 to + 150 |        | °C   |
| T <sub>j</sub>   | Maximum operating junction temperature                        | 150           |        |      |

TURBOSWITCH2 is a trademark of STMicroelectronics

## DMV1500H

### THERMAL RESISTANCES

| Symbol               | Parameter                   | Value | Unit |
|----------------------|-----------------------------|-------|------|
| R <sub>th(j-c)</sub> | Damper junction to case     | 3.6   | °C/W |
| R <sub>th(j-c)</sub> | Modulation junction to case | 6     |      |
| R <sub>th(c)</sub>   | Coupling                    | 0.2   |      |

### STATIC ELECTRICAL CHARACTERISTICS OF THE DAMPER DIODES

| Symbol            | Parameter               | Test conditions        | Value                 |      |                        |      | Unit |  |
|-------------------|-------------------------|------------------------|-----------------------|------|------------------------|------|------|--|
|                   |                         |                        | T <sub>j</sub> = 25°C |      | T <sub>j</sub> = 125°C |      |      |  |
|                   |                         |                        | Typ.                  | Max. | Typ.                   | Max. |      |  |
| V <sub>F</sub> *  | Forward voltage drop    | I <sub>F</sub> = 6 A   | 1.5                   | 2.3  | 1.25                   | 1.7  | V    |  |
| I <sub>R</sub> ** | Reverse leakage current | V <sub>R</sub> = 1500V |                       | 100  | 100                    | 1000 | µA   |  |

Pulse test : \* tp = 380 µs, δ < 2%

\*\*tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses of the DAMPER diode use the following equations :

$$P = 1.35 \times I_F(AV) + 0.059 \times I_F^2(RMS)$$

### STATIC ELECTRICAL CHARACTERISTICS OF THE MODULATION DIODE

| Symbol            | Parameter               | Test conditions       | Value                 |      |                        |      | Unit |  |
|-------------------|-------------------------|-----------------------|-----------------------|------|------------------------|------|------|--|
|                   |                         |                       | T <sub>j</sub> = 25°C |      | T <sub>j</sub> = 125°C |      |      |  |
|                   |                         |                       | Typ.                  | Max. | Typ.                   | Max. |      |  |
| V <sub>F</sub> *  | Forward voltage drop    | I <sub>F</sub> = 3A   |                       | 1.8  | 1.1                    | 1.4  | V    |  |
| I <sub>R</sub> ** | Reverse leakage current | V <sub>R</sub> = 600V |                       | 20   | 3                      | 50   | µA   |  |

Pulse test : \* tp = 380 µs, δ < 2%

\*\*tp = 5 ms, δ < 2%

To evaluate the maximum conduction losses of the MODULATION diode use the following equations :

$$P = 1.2 \times I_F(AV) + 0.066 \times I_F^2(RMS)$$

### RECOVERY CHARACTERISTICS OF THE DAMPER DIODE

| Symbol          | Parameter             | Test conditions  |                       | Value |      | Unit |
|-----------------|-----------------------|--|-----------------------|-------|------|------|
|                 |                       |  |                       | Typ.  | Max. |      |
| t <sub>rr</sub> | Reverse recovery time | I <sub>F</sub> = 100mA<br>I <sub>R</sub> = 100mA<br>I <sub>RR</sub> = 10mA   | T <sub>j</sub> = 25°C | 650   |      | ns   |
| t <sub>rr</sub> | Reverse recovery time | I <sub>F</sub> = 1A<br>dI <sub>F</sub> /dt = -50A/µs<br>V <sub>R</sub> = 30V | T <sub>j</sub> = 25°C | 95    | 125  | ns   |

## RECOVERY CHARACTERISTICS OF THE MODULATION DIODE

| Symbol   | Parameter             | Test conditions  |                          | Value |      | Unit |
|----------|-----------------------|--|--------------------------|-------|------|------|
|          |                       |  |                          | Typ.  | Max. |      |
| $t_{rr}$ | Reverse recovery time | $I_F = 100\text{mA}$<br>$I_R = 100\text{mA}$<br>$I_{RR} = 10\text{mA}$         | $T_j = 25^\circ\text{C}$ | 110   | 350  | ns   |
| $t_{rr}$ | Reverse recovery time | $I_F = 1\text{A}$<br>$dI_F/dt = -50\text{A}/\mu\text{s}$<br>$V_R = 30\text{V}$ | $T_j = 25^\circ\text{C}$ |       | 50   | ns   |

## TURN-ON SWITCHING CHARACTERISTICS OF THE DAMPER DIODE

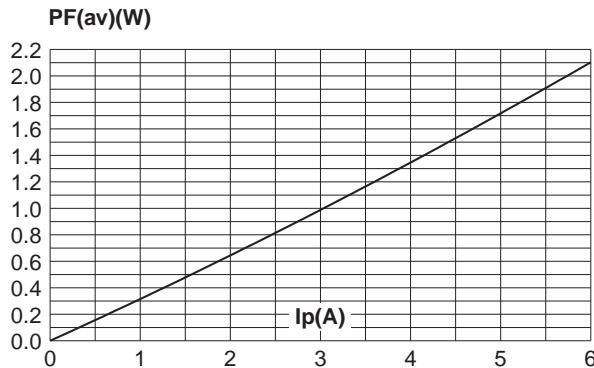
| Symbol   | Parameter             | Test conditions   |                           | Value |      | Unit |
|----------|-----------------------|---|---------------------------|-------|------|------|
|          |                       |   |                           | Typ.  | Max. |      |
| $t_{fr}$ | Forward recovery time | $I_F = 6\text{A}$<br>$dI_F/dt = 80\text{A}/\mu\text{s}$<br>$V_{FR} = 3\text{V}$ | $T_j = 100^\circ\text{C}$ | 350   |      | ns   |
| $V_{FP}$ | Peak forward voltage  | $I_F = 6\text{A}$<br>$dI_F/dt = 80\text{A}/\mu\text{s}$                         | $T_j = 100^\circ\text{C}$ | 18    | 25   | V    |

## TURN-ON SWITCHING CHARACTERISTICS OF THE MODULATION DIODE

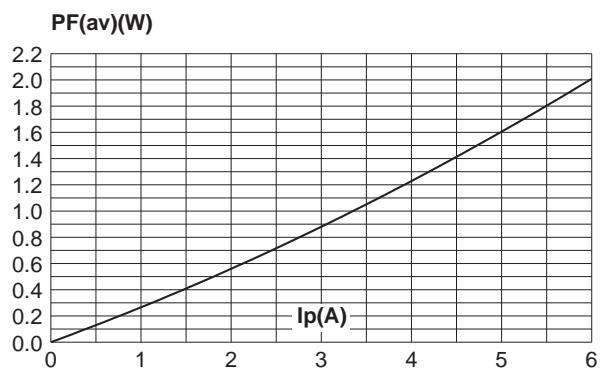
| Symbol   | Parameter             | Test conditions   |                           | Value |      | Unit |
|----------|-----------------------|---|---------------------------|-------|------|------|
|          |                       |   |                           | Typ.  | Max. |      |
| $t_{fr}$ | Forward recovery time | $I_F = 3\text{A}$<br>$dI_F/dt = 80\text{A}/\mu\text{s}$<br>$V_{FR} = 2\text{V}$ | $T_j = 100^\circ\text{C}$ |       | 240  | ns   |
| $V_{FP}$ | Peak forward voltage  | $I_F = 3\text{A}$<br>$dI_F/dt = 80\text{A}/\mu\text{s}$                         | $T_j = 100^\circ\text{C}$ |       | 8    | V    |

## DMV1500H

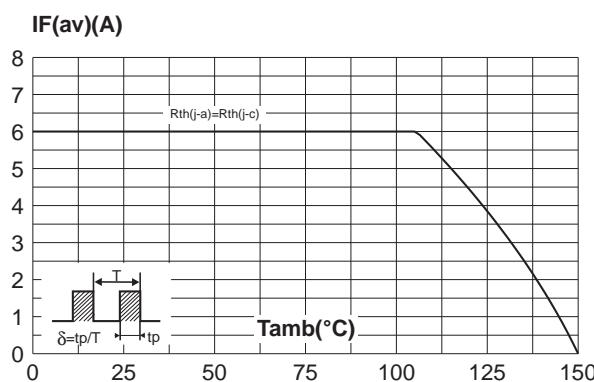
**Fig. 1-1:** Power dissipation versus peak forward current (triangular waveform,  $\delta = 0.45$ ) (damper diode).



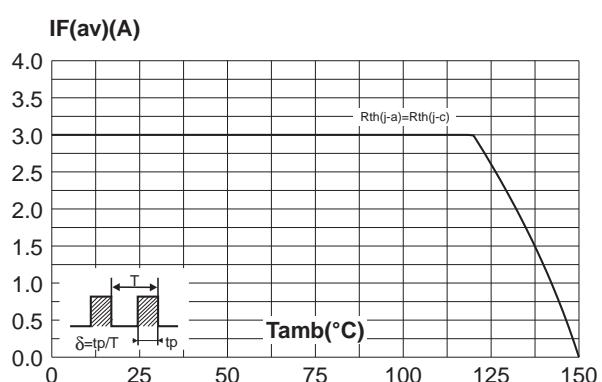
**Fig. 1-2:** Power dissipation versus peak forward current (triangular waveform,  $\delta = 0.45$ ) (modulation diode).



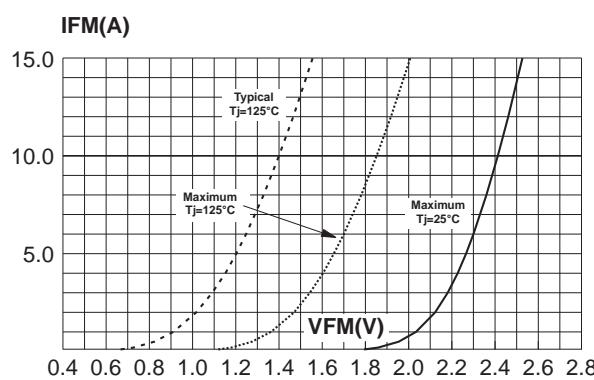
**Fig. 2-1:** Average forward current versus ambient temperature (damper diode).



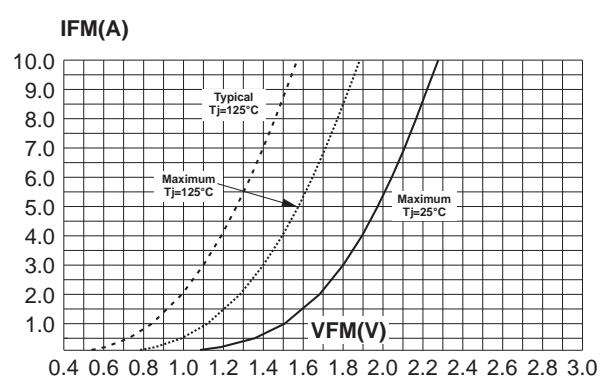
**Fig. 2-2:** Average forward current versus ambient temperature (modulation diode).



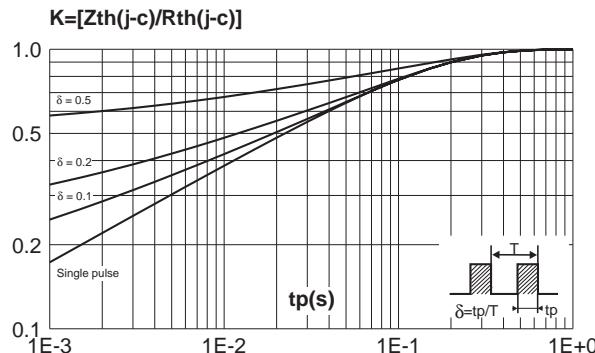
**Fig. 3-1:** Forward voltage drop versus forward current (damper diode).



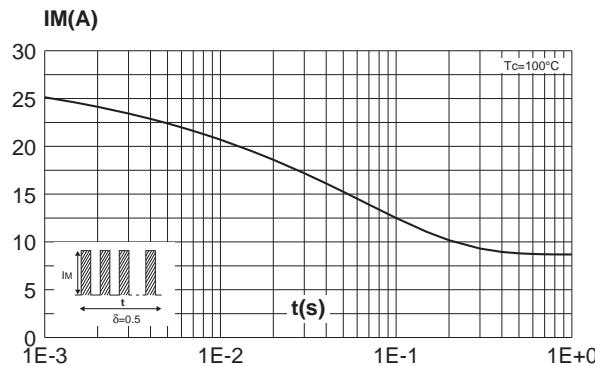
**Fig. 3-2:** Forward voltage drop versus forward current (modulation diode).



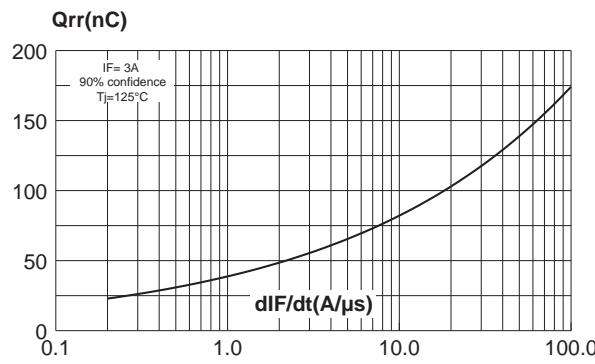
**Fig. 4:** Relative variation of thermal impedance junction to case versus pulse duration.



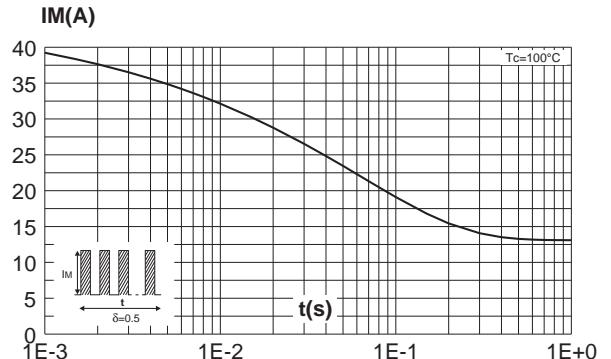
**Fig. 5-2:** Non repetitive surge peak forward current versus overload duration (modulation diode).



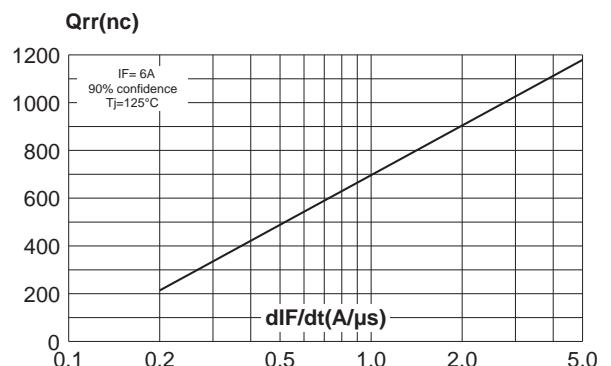
**Fig. 6-2:** Reverse recovery charges versus  $dIF/dt$  (modulation diode).



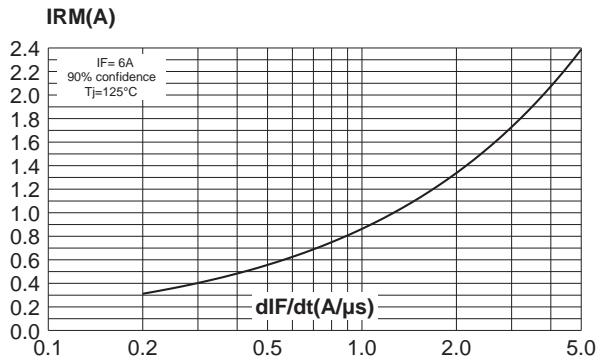
**Fig. 5-1:** Non repetitive surge peak forward current versus overload duration (damper diode).



**Fig. 6-1:** Reverse recovery charges versus  $dIF/dt$  (damper diode).

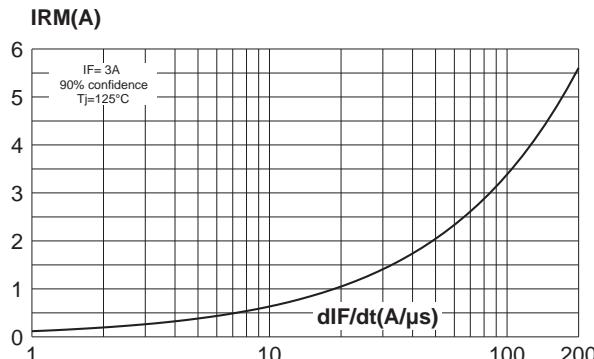


**Fig. 7-1:** Reverse recovery current versus  $dIF/dt$  (damper diode).

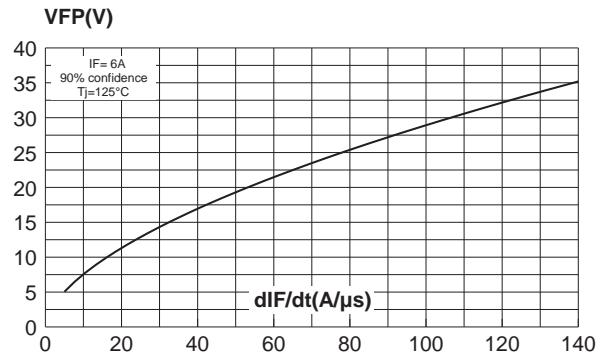


## DMV1500H

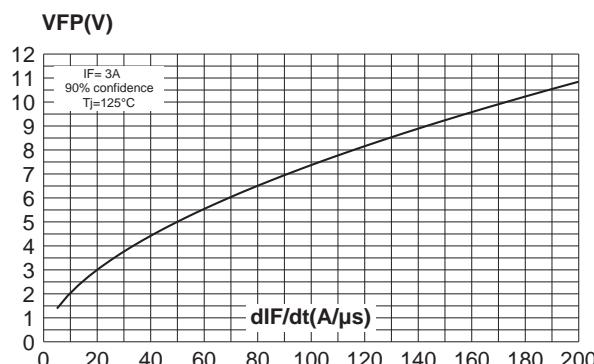
**Fig. 7-2:** Reverse recovery current versus dIF/dt (modulation diode).



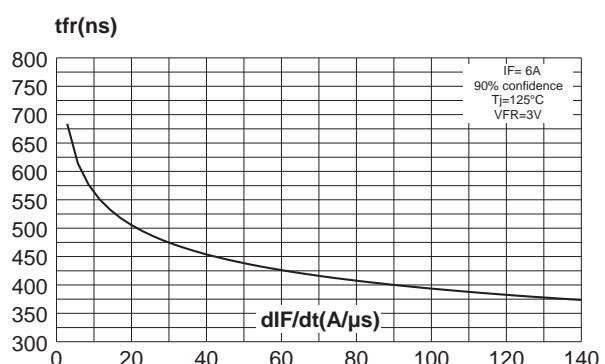
**Fig. 8-1:** Transient peak forward voltage versus dIF/dt (damper diode).



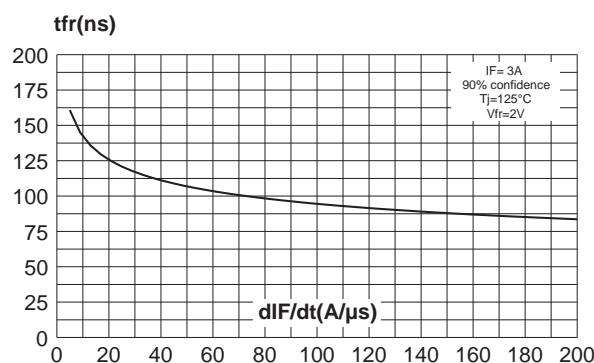
**Fig. 8-2:** Transient peak forward voltage versus dIF/dt (modulation diode).



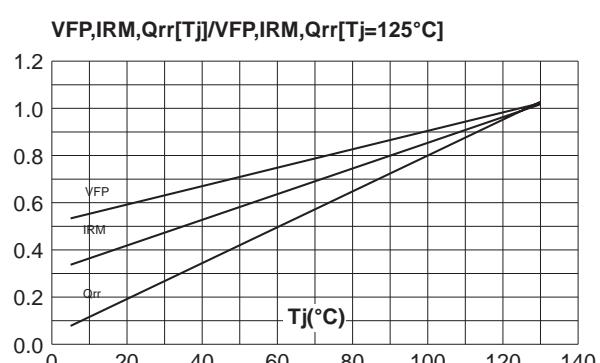
**Fig. 9-1:** Forward recovery time versus dIF/dt (damper diode).



**Fig. 9-2:** Forward recovery time versus dIF/dt (modulation diode).

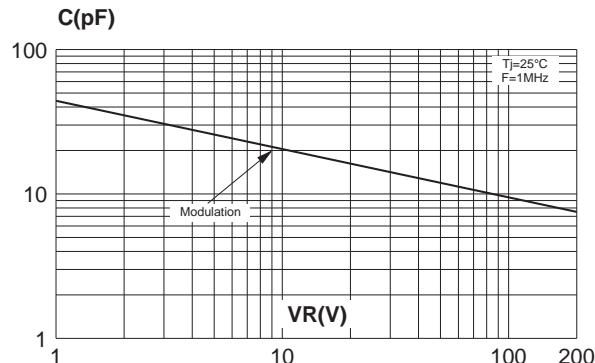


**Fig. 10:** Dynamic parameters versus junction temperature (damper & modulation diodes).

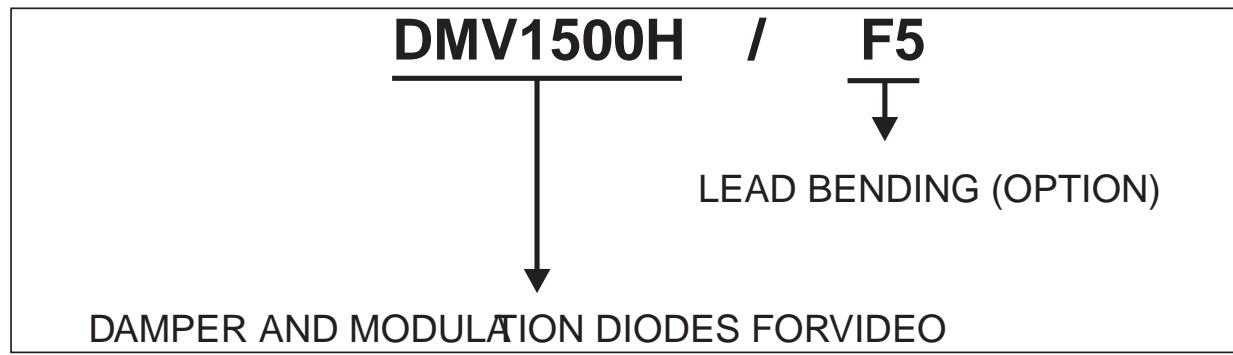


## DMV1500H

**Fig. 11:** Junction capacitance versus reverse voltage applied (typical values) (damper & modulation diodes).

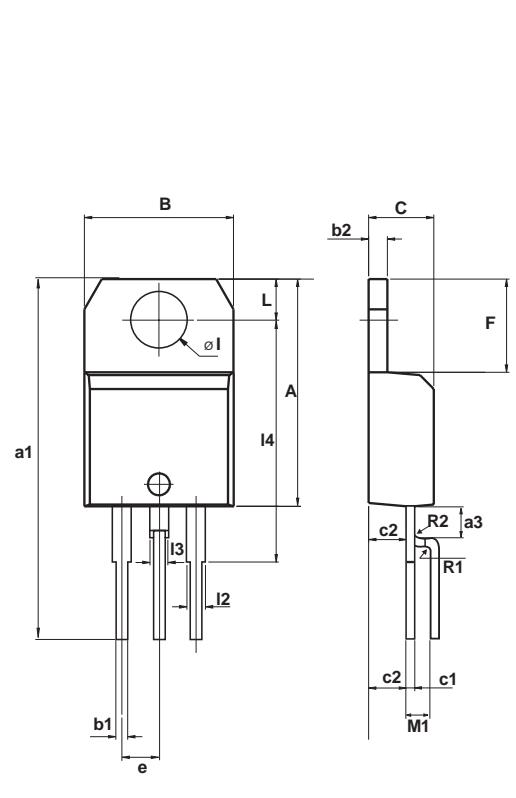


## ORDERING INFORMATION



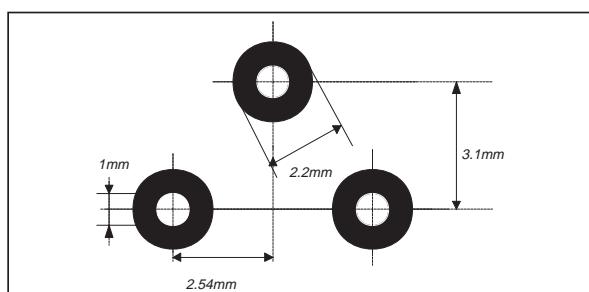
# DMV1500H

## PACKAGE MECHANICAL DATA TO-220AB F5 OPTION



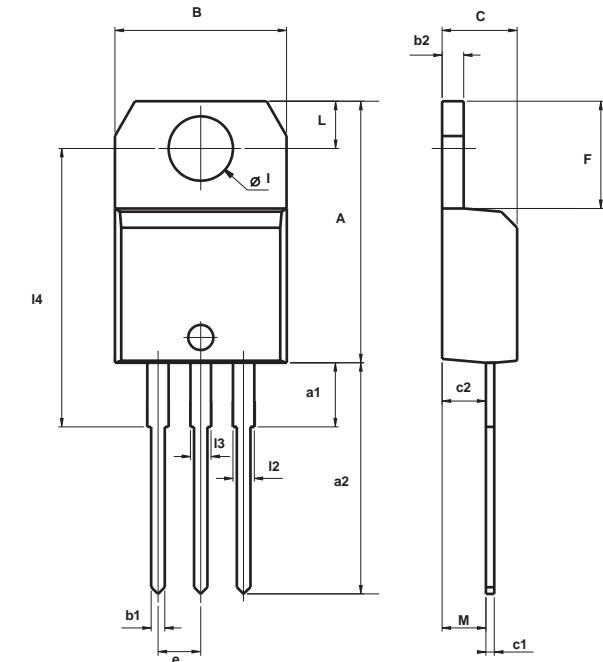
| REF. | DIMENSIONS  |       |            |       |
|------|-------------|-------|------------|-------|
|      | Millimeters |       | Inches     |       |
|      | Min.        | Max.  | Min.       | Max.  |
| A    | 15.20       | 15.90 | 0.598      | 0.625 |
| a1   | 24.16       | 26.90 | 0.951      | 1.059 |
| a3   | 1.65        | 2.41  | 0.064      | 0.094 |
| B    | 10.00       | 10.40 | 0.393      | 0.409 |
| b1   | 0.61        | 0.88  | 0.024      | 0.034 |
| b2   | 1.23        | 1.32  | 0.048      | 0.051 |
| C    | 4.40        | 4.60  | 0.173      | 0.181 |
| c1   | 0.49        | 0.70  | 0.019      | 0.027 |
| c2   | 2.40        | 2.72  | 0.094      | 0.107 |
| e    | 2.40        | 2.70  | 0.094      | 0.106 |
| F    | 6.20        | 6.60  | 0.244      | 0.259 |
| I    | 3.75        | 3.85  | 0.147      | 0.151 |
| L    | 2.65        | 2.95  | 0.104      | 0.116 |
| I2   | 1.14        | 1.70  | 0.044      | 0.066 |
| I3   | 1.14        | 1.70  | 0.044      | 0.066 |
| I4   | 15.80       | 16.80 | 0.622      | 0.661 |
|      | 16.40 typ.  |       | 0.645 typ. |       |
| M1   | 2.92        | 3.30  | 0.114      | 0.129 |
| R1   | 1.40 typ.   |       | 0.055 typ. |       |
| R2   | 1.40 typ.   |       | 0.055 typ. |       |

## PRINTED CIRCUIT LAYOUT FOR F5 LAYOUT



- Cooling method: by conduction (c)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

**PACKAGE MECHANICAL DATA**  
TO-220AB



| REF. | DIMENSIONS  |       |       |        |       |       |
|------|-------------|-------|-------|--------|-------|-------|
|      | Millimeters |       |       | Inches |       |       |
|      | Min.        | Typ.  | Max.  | Min.   | Typ.  | Max.  |
| A    | 15.20       |       | 15.90 | 0.598  |       | 0.625 |
| a1   |             | 3.75  |       |        | 0.147 |       |
| a2   | 13.00       |       | 14.00 | 0.511  |       | 0.551 |
| B    | 10.00       |       | 10.40 | 0.393  |       | 0.409 |
| b1   | 0.61        |       | 0.88  | 0.024  |       | 0.034 |
| b2   | 1.23        |       | 1.32  | 0.048  |       | 0.051 |
| C    | 4.40        |       | 4.60  | 0.173  |       | 0.181 |
| c1   | 0.49        |       | 0.70  | 0.019  |       | 0.027 |
| c2   | 2.40        |       | 2.72  | 0.094  |       | 0.107 |
| e    | 2.40        |       | 2.70  | 0.094  |       | 0.106 |
| F    | 6.20        |       | 6.60  | 0.244  |       | 0.259 |
| I    | 3.75        |       | 3.85  | 0.147  |       | 0.151 |
| I4   | 15.80       | 16.40 | 16.80 | 0.622  | 0.646 | 0.661 |
| L    | 2.65        |       | 2.95  | 0.104  |       | 0.116 |
| I2   | 1.14        |       | 1.70  | 0.044  |       | 0.066 |
| I3   | 1.14        |       | 1.70  | 0.044  |       | 0.066 |
| M    |             | 2.60  |       |        | 0.102 |       |

- cooling method: by conduction (c)
- Recommended torque value: 0.8 m.N.
- Maximum torque value: 1 m.N.

| Type       | Marking  | Package  | Weight | Base qty | Delivery mode |
|------------|----------|----------|--------|----------|---------------|
| DMV1500H   | DMV1500H | TO-220AB | 2.2 g. | 50       | Tube          |
| DMV1500HF5 |          |          |        |          |               |

- Epoxy meets UL94, V0

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